# VB60170G

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Vishay General Semiconductor

### **Dual High-Voltage Trench MOS Barrier Schottky Rectifier**

Ultra Low  $V_F = 0.50$  V at  $I_F = 5$  A

# TO-263AB VB60170G

### **FEATURES**

- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses
- · High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum RoHS peak of 245 °C COMPLIANT
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

### **TYPICAL APPLICATIONS**

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

### **MECHANICAL DATA**

### Case: TO-263AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

<b>MAXIMUM RATINGS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	VB60170G	UNIT	
Maximum repetitive peak reverse voltage		V <sub>RRM</sub>	170	V	
Maximum average forward rectified current (fig. 1)	per device	I <sub>F(AV)</sub>	60	A	
	per diode		30		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load		I <sub>FSM</sub>	210	A	
Voltage rate of change (rated V <sub>R</sub> )		dV/dt	10 000	V/µs	
Operating junction and storage temperature range		T <sub>J</sub> , T <sub>STG</sub>	- 40 to + 175	°C	

# PIN 1 O-

HEATSINK

2 x 30 A

170 V

210 A

0.72 V

175 °C

**PRIMARY CHARACTERISTICS** 

IF(AV)

V<sub>RRM</sub>

IFSM

 $V_F$  at  $I_F = 30$  A

T<sub>J</sub> max.

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<b>ELECTRICAL CHARACTERISTICS</b> ( $T_A = 25$ °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode	I <sub>F</sub> = 5 A	T <sub>A</sub> = 25 °C	V <sub>F</sub> (1)	0.65	-	V	
	I <sub>F</sub> = 15 A			0.78	-		
	I <sub>F</sub> = 30 A			0.87	1.02		
	$I_F = 5 A$	T <sub>A</sub> = 125 °C		0.50	-		
	I <sub>F</sub> = 15 A			0.62	-		
	I <sub>F</sub> = 30 A			0.72	0.80		
Reverse current per diode	V <sub>R</sub> = 136 V	T <sub>A</sub> = 25 °C	I <sub>R</sub> (2)	1.5	-	μA	
		T <sub>A</sub> = 125 °C		2.5	-	mA	
	V <sub>R</sub> = 170 V	T <sub>A</sub> = 25 °C		-	450	μA	
		T <sub>A</sub> = 125 °C		5	50	mA	

#### Notes

<sup>(1)</sup> Pulse test: 300 µs pulse width, 1 % duty cycle

<sup>(2)</sup> Pulse test: Pulse width  $\leq$  20 ms

<b>THERMAL CHARACTERISTICS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted)					
PARAMETER		SYMBOL	VB60170G	UNIT	
Typical thermal resistance	per diode	$R_{ extsf{ heta}JC}$	1.0	°C/W	
	per device		0.7	C/W	

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-263AB	VB60170G-E3/4W	1.38	4W	50/tube	Tube	
TO-263AB	VB60170G-E3/8W	1.38	8W	800/reel	Tape and reel	

### **RATINGS AND CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25 °C unless otherwise noted)

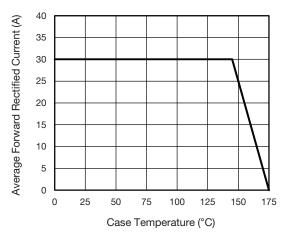


Fig. 1 - Maximum Forward Current Derating Curve

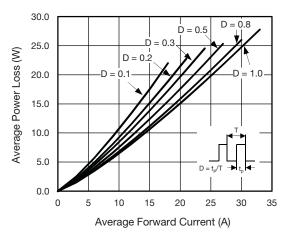


Fig. 2 - Forward Power Loss Characteristics Per Diode

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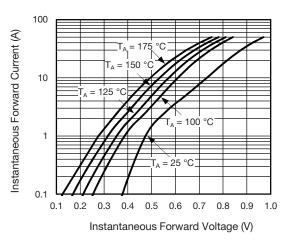
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Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

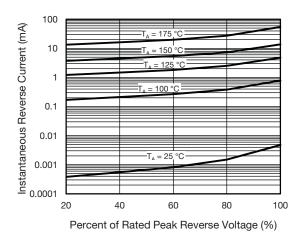
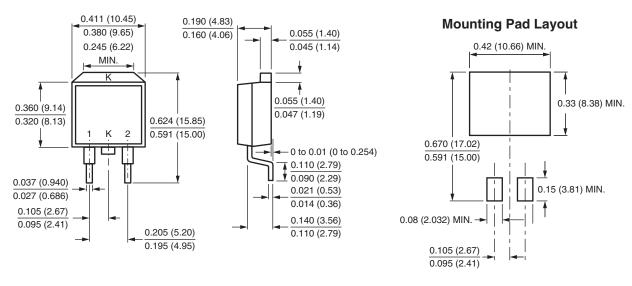


Fig. 4 - Typical Reverse Characteristics Per Diode





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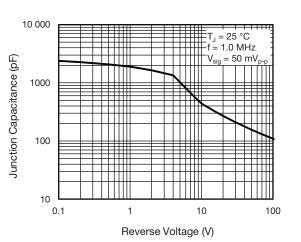


Fig. 5 - Typical Junction Capacitance Per Diode

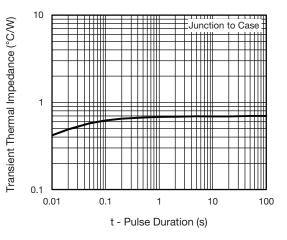


Fig. 6 - Typical Transient Thermal Impedance Per Diode



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